TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

2SK2699

Chopper Regulator, DC-DC Converter and Motor Drive Applications

• Low drain–source ON resistance : RDS (ON) = 0.5 Ω (typ.)

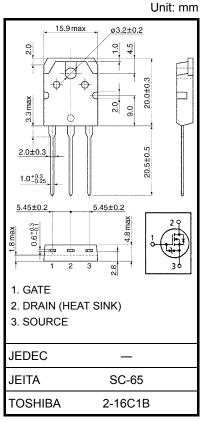
• High forward transfer admittance : $|Y_{fs}| = 11 S \text{ (typ.)}$

• Low leakage current : $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 600 \text{ V)}$

• Enhancement mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

| Characteris | stics | Symbol | Rating | Unit | |
|-------------------------|------------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 600 | V | |
| Drain-gate voltage (Ro | _{SS} = 20 kΩ) | V_{DGR} | 600 | V | |
| Gate-source voltage | | V _{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | ΙD | 12 | Α | |
| Diam current | Pulse (Note 1) | I _{DP} | 48 | Α | |
| Drain power dissipation | n (Tc = 25°C) | P _D | 150 | W | |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 605 | mJ | |
| Avalanche current | | I _{AR} | 12 | Α | |
| Repetitive avalanche e | nergy (Note 3) | E _{AR} | 15 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature ra | ange | T _{stg} | -55 to 150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 7.35 mH, R_G = 25 Ω , I_{AR} = 12 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

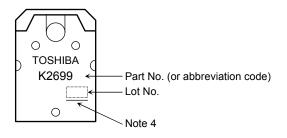
Electrical Characteristics (Ta = 25°C)

| Charac | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|----------------------|---|-----|------|------|------|
| Gate leakage cu | irrent | I _{GSS} | V _{GS} = ±25 V, V _{DS} = 0 V | | _ | ±10 | μΑ |
| Gate-source bre | eakdown voltage | V (BR) GSS | $I_G = \pm 10 \mu A, V_{DS} = 0 V$ | ±30 | _ | _ | V |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 600 V, V _{GS} = 0 V | _ | _ | 100 | μΑ |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 600 | _ | _ | V |
| Gate threshold v | oltage | V_{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source O | N resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 6 A | _ | 0.5 | 0.65 | Ω |
| Forward transfer | r admittance | Y _{fs} | V _{DS} = 10 V, I _D = 6 A | 6.0 | 11.0 | _ | S |
| Input capacitano | e | C _{iss} | | _ | 2600 | _ | |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 270 | _ | pF |
| Output capacitance | | Coss | | | 820 | _ | |
| Switching time | Rise time | t _r | V_{GS} V_{OV} V_{OU} V_{OU} V_{DD} V_{OU} V_{DD} | _ | 45 | _ | |
| | Turn-on time | t _{on} | | _ | 75 | _ | ne |
| | Fall time | t _f | | _ | 65 | _ | ns |
| | Turn-off time | t _{off} | Duty $\leq 1\%$, $t_{\rm w} = 10 \mu \rm s$ | _ | 270 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | | | 58 | | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 480 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 12 \text{ A}$ | | 37 | _ | nC |
| Gate-drain ("miller") Charge | | Q _{gd} | | | 21 | _ | |

Source-Drain Diode Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 12 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 48 | Α |
| Forward voltage (diode) | V_{DSF} | I _{DR} = 12 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 12 A, V _{GS} = 0 V | _ | 460 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} / dt = 100 Å / μs | _ | 4.8 | _ | μC |

Marking

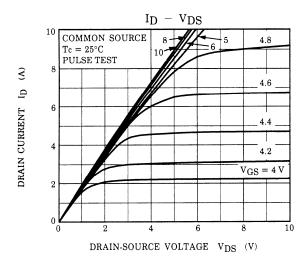


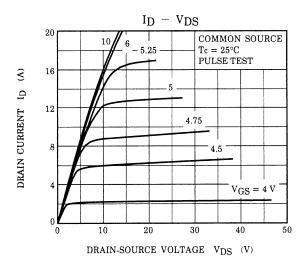
Note 4: A line under a Lot No. identifies the indication of product Labels.

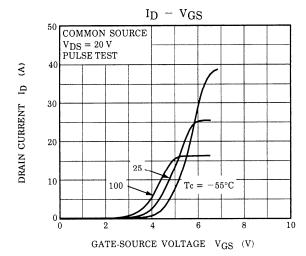
Not underlined: [[Pb]]/INCLUDES > MCV

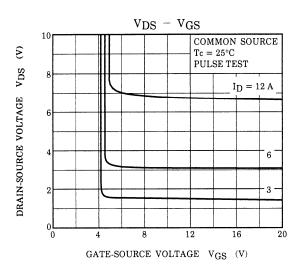
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

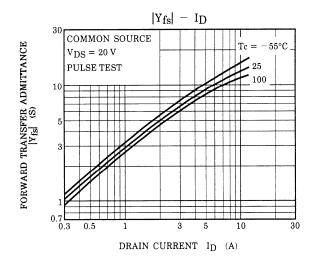
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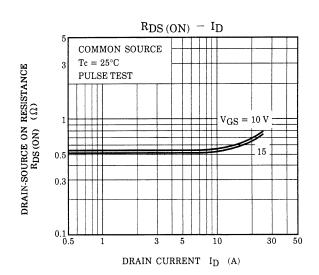




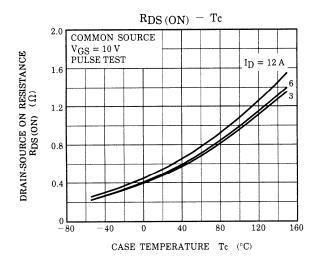


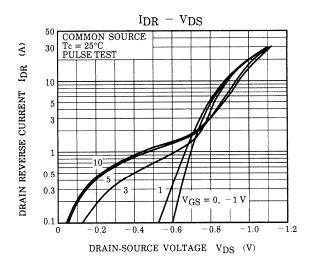


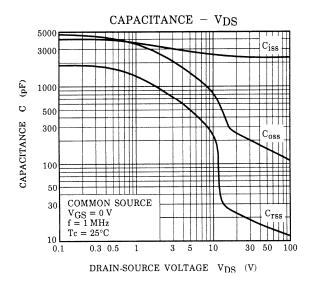


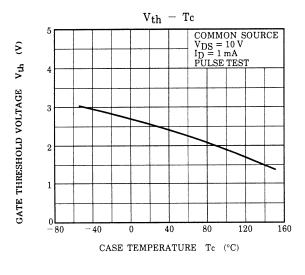


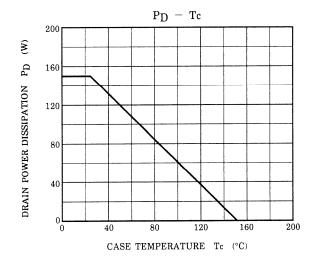
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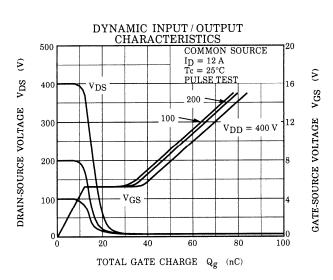


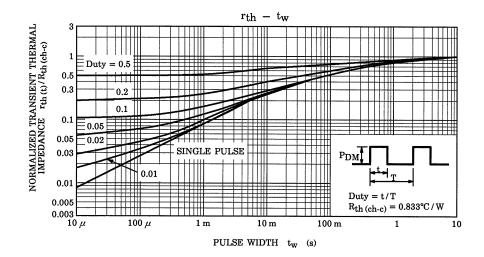


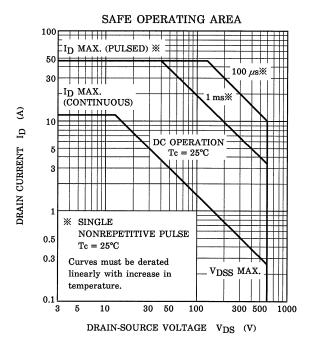


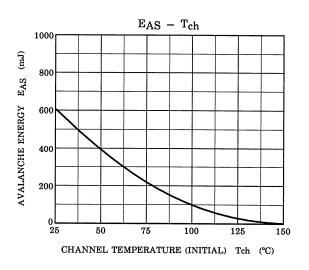


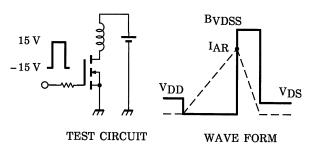












$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 90~V,~L = 7.35~mH \end{aligned} \quad E_{AS} &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right) \end{aligned}$$

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